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PJQ4453EP-AU

40V P-Channel Enhancement Mode MOSFET

Voltage

Current -55 A

Features

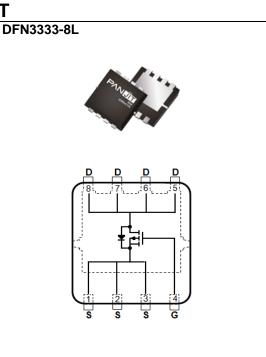
• Rds(on), Vgs@-10V, Id@-10A<11.6mΩ

-40 V

- $R_{DS(ON)}$, V_{GS} @-4.5V, I_D @-6A<17.6m Ω
- 100% UIS tested
- Reliable and Rugged
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN3333-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.03 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	-40	V
Gate-Source Voltage		V _{GS}	±25	
Continuous Drain Current ^(Note 3)	T _C =25°C		-55	
	Tc=100°C	I _D	-39	А
Pulsed Drain Current ^(Note 1)	T _C =25°C	I _{DM}	-162	
Power Dissipation	T _C =25°C		63	14/
	Tc=100°C	PD	31	W
Continuous Drain Current ^(Note 4)	T _A =25°C		-11	٥
	T _A =70°C	ID	-9.2	— A
Power Dissipation	T _A =25°C	Pp	2.5	— w
	T _A =70°C	PD	1.8	VV
Single Pulse Avalanche Energy ^(Note 5)		Eas	110	mJ
Operating Junction and Storage Temperature Range		TJ,TSTG	-55~175	°C
Thermal Resistance ^(Note 4)	Junction to Case	R _{θJC}	2.4	°C/W
	Junction to Ambient	R _{θJA}	60	C/vv



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Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static		-	-			-	
Drain-Source Breakdown Voltage	BV _{DSS}	V_{GS} =0V, I_{D} =-250uA	-40	-	-	V	
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-1	-1.7	-2.5		
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-10A	-	9.3	11.6	mΩ	
		V _{GS} =-4.5V, I _D =-6A	-	13.5	17.6		
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =-40V, V_{GS} =0V	-	-	-1	uA	
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±25V, V _{DS} =0V	-	-	±100	nA	
Dynamic ^(Note 6)							
Total Gate Charge	Qg		-	56	-		
Gate-Source Charge	Qgs	V _{DS} =-32V, I _D =-10A,	-	8.4	-	nC	
Gate-Drain Charge	Q_{gd}	V _{GS} =-10V	-	18	-		
Input Capacitance	Ciss		-	2858	-	pF	
Output Capacitance	Coss	V_{DS} =-25V, V_{GS} =0V,	-	228	-		
Reverse Transfer Capacitance	Crss	f=1MHz	-	179	-		
Gate resistance	Rg	f=1MHz	-	2.9	-	Ω	
Turn-On Delay Time	td _(on)		-	11	-		
Turn-On Rise Time	tr	V _{DS} =-32V, I _D =-10A,	-	10	-		
Turn-Off Delay Time	td _(off)	V _{GS} =-10V, R _G =3Ω	-	47	-	ns	
Turn-Off Fall Time	tf		-	24	-		
Drain-Source Diode		·	•				
Diode Forward Current	Is	T 05°0	-	-	-55		
Pulsed Diode Forward Current	I _{SM}	T _C =25 [°] C	-	-	-162	A	
Diode Forward Voltage	V _{SD}	Is=-20A, V _{GS} =0V	-	-0.85	-1.3	V	
Reverse Recovery Time	Trr	V _{GS} =0V, I _S =-20A	-	29	-	ns	
Reverse Recovery Charge	Qrr	dls/dt=100A/us	-	24	-	nC	

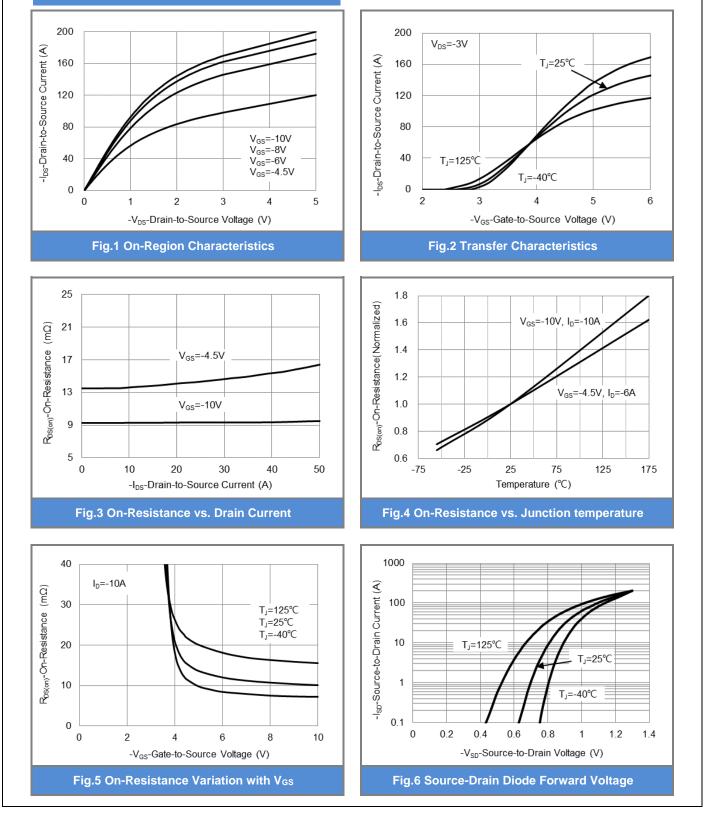
NOTES :

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. $R_{\theta,JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 5. The test condition is L=0.5mH, I_{AS} =-21A, V_{DD} =-30V, V_{GS} =-10V, Starting T_J =25°C.
- 6. Guaranteed by design, not subject to production testing.

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TYPICAL CHARACTERISTIC CURVES

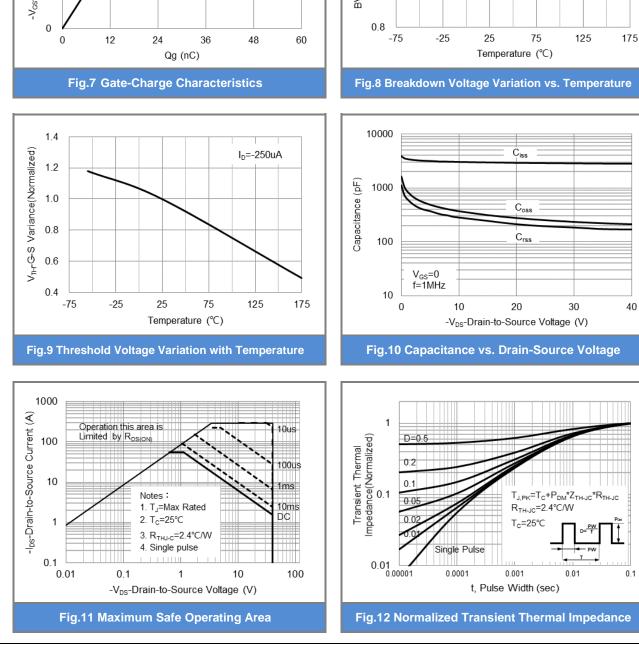




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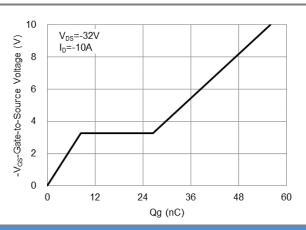
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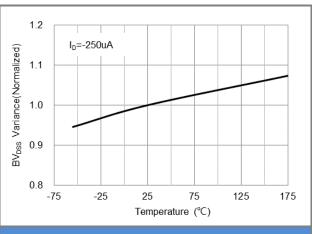
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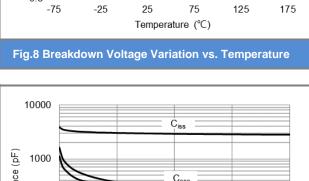


TYPICAL CHARACTERISTIC CURVES

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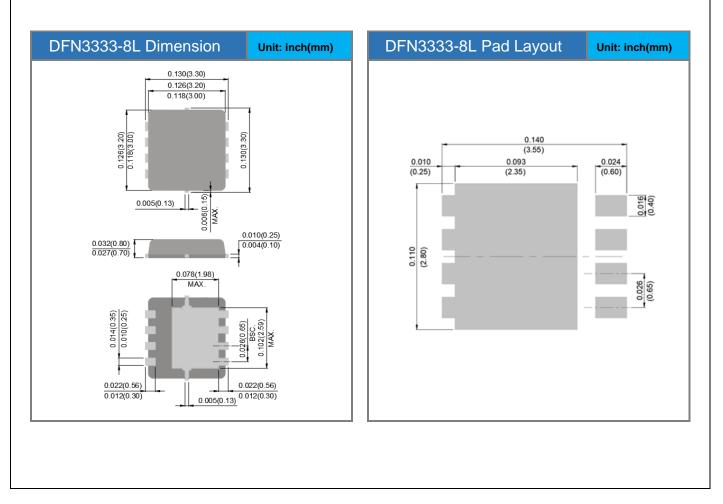


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Product and Packing Information

Part No.	Package Type	Packing Type	Marking	
PJQ4453EP-AU	DFN3333-8L	5K pcs / 13" reel	453E	

Packaging Information & Mounting Pad Layout





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